

CRMLTL2N7003K

N-Channel 60V, 1.8Ω Typ. Power MOSFET

Description

Features

• 60V, 0.3A

 $R_{DS(ON)}$ Typ = 1.8 Ω @ V_{GS} = 10V

 $R_{DS(ON)}$ Typ = 2.5 Ω @ V_{GS} = 4.5V

- Advanced Trench Technology
- Excellent R_{DS(ON)} and Low Gate Charge
- Lead Free
- ESD Protected: 2KV

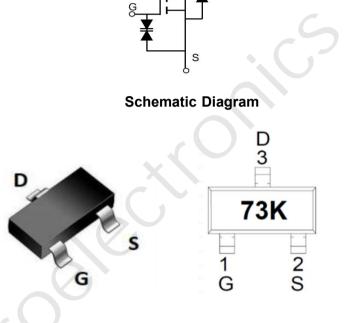
Battery Operated Systems

• Direct logic-level Interface:

Application

TTL/CMOS

• Solid-State Relays



Marking and Pin Assignment

Package Marking and Ordering Information

Device	Marking	Package	Outline	Reel Size	Reel (pcs)	Per Carton (pcs)
CRMLTL2N7003K	73K	SOT-23	TAPING	7"	3000	120000

Absolute Maximum Ratings (@ T_J = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V _{DS}	Drain-to-Source Voltage		60	V
V _{GS}	Gate-to-Source Voltage		±20	V
	Continuous Drain Current $T_{A} = 25^{\circ}C$	0.3	А	
Ι _D	Continuous Drain Current	T _A = 100°C	0.18	А
I _{DM}	Pulsed Drain Current ⁽¹⁾		1.2	А
P _D	Power Dissipation	T _A = 25°C	0.35	W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient ⁽²⁾		357	°C/W
Τ _J , Τ _{stg}	Junction & Storage Temperature Rang	e	-55 to 150	°C



Electrical Characteristics (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Chara	acteristics					
V _{(BR)DSS}	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	60	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60V, V _{GS} = 0V	-	-	1.0	μA
I _{GSS}	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±800	nA
On Chara	acteristics				6	
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} , I_D = 250 μ A	1	1.6	2.2	V
R _{DS(ON)}		V_{GS} = 10V, I_{D} = 0.3A	-	1.8	2.2	Ω
	Static Drain-Source ON-Resistance ⁽³⁾	V_{GS} = 4.5V, I _D = 0.2A	-	2.5	3	Ω
Dynamic	Characteristics					
C _{iss}	Input Capacitance		-	18	-	pF
C_{oss}	Output Capacitance	V _{GS} = 0V, V _{DS} = 25V, f = 1MHz	X-\	3.3	-	pF
C _{rss}	Reverse Transfer Capacitance		C	2	-	pF
Qg	Total Gate Charge	0	<u> </u>	1.7	-	nC
Q_{gs}	Gate Source Charge	$V_{GS} = 0$ to 10V $V_{DS} = 10V$, $I_D = 0.3A$) -	0.3	-	nC
Q_gd	Gate Drain("Miller") Charge		-	0.6	-	nC
Switchin	g Characteristics					
t _{d(on)}	Turn-On DelayTime		-	2	-	ns
t _r	Turn-On Rise Time	V _{GS} = 10V, V _{DD} = 10V	-	15	-	ns
$t_{d(off)}$	Turn-Off DelayTime	I_D = 0.2A, R_{GEN} = 10 Ω	-	7	-	ns
t _f	Turn-Off Fall Time		-	20	-	ns
Drain-So	urce Diode Characteristics and I	Max Ratings				
I _S	Maximum Continuous Drain to Source Diode Forward Current			-	0.3	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	1.2	А
V_{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _S = 0.3A	-	-	1.2	V
Notes:	1. Repetitive Rating: Pulse Width Limited by Maxir	num Junction Temperature.				

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2. $R_{\theta JA}$ is measured with the device mounted on a 1inch² pad of 2oz copper FR4 PCB

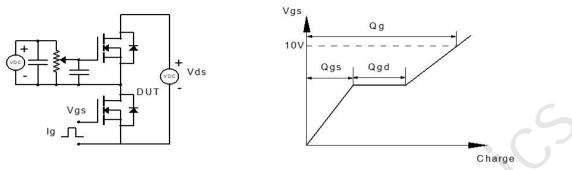
3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%.



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Test Circuit





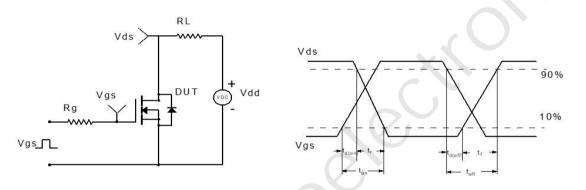


Figure 2: Resistive Switching Test Circuit & Waveform

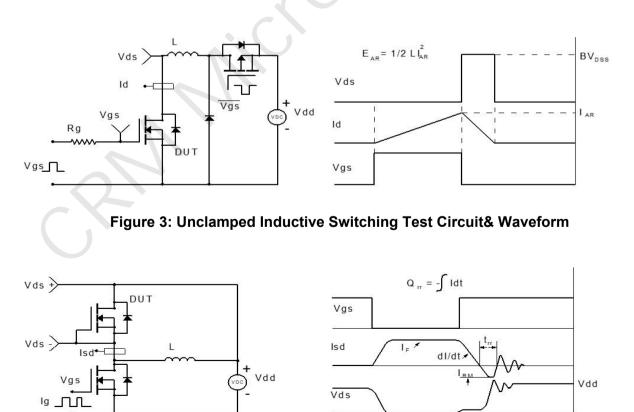
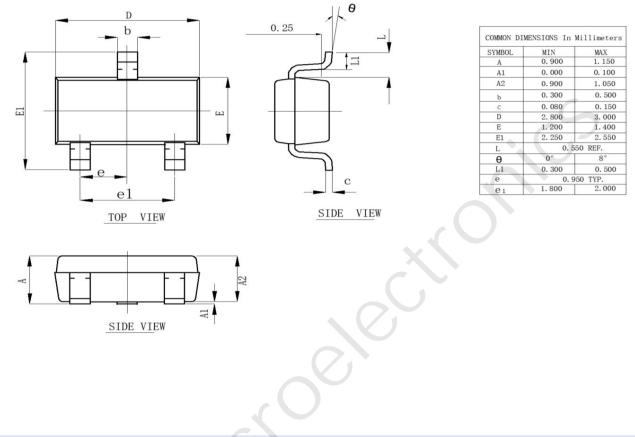


Figure 4: Diode Recovery Test Circuit & Waveform



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Package Mechanical Data(SOT-23)



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